

Special Issue

Volume II: Semiconductor Power Devices

Message from the Guest Editors

This Special Issue aims to gather contributions defining the state-of-the-art in Wide-band-gap (WBG) power device design, fabrication technology, packaging and thermal management, application and reliability validation: Original contributions and review papers alike are solicited in all relevant areas. Dr. Andrea Irace

Keywords

- Silicon carbide (SiC)
- Gallium nitride (GaN)
- Gallium Oxide (Ga₂O₃)
- Diamond (C)
- Semiconductor power devices
- MOSFETs
- HEMTs
- Power converters
- Power modules
- Packaging
- Thermal management/cooling
- Reliability

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Deadline for manuscript submissions

closed (30 June 2019)



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Energies is an international, open access journal in energy engineering and research. The journal publishes original papers, review articles, technical notes, and letters. Authors are encouraged to submit manuscripts which bridge the gaps between research, development and implementation. The journal provides a forum for information on research, innovation, and demonstration in the areas of energy conversion and conservation, the optimal use of energy resources, optimization of energy processes, mitigation of environmental pollutants, and sustainable energy systems.

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